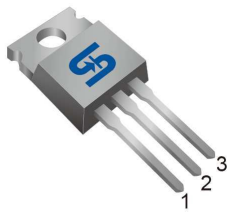


TO-220



Pin Definition:

1. Gate
2. Drain
3. Source

PRODUCT SUMMARY

| V _{DS} (V) | R _{DS(on)} (mΩ) | I _D (A) |
|---------------------|---------------------------|--------------------|
| 100 | 10 @ V _{GS} =10V | 81 |

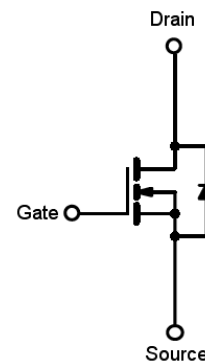
Features

- Advanced Trench Technology
- Low R_{DS(ON)} 10mΩ (Max.)
- Low gate charge typical @ 154nC (Typ.)
- Low Crss typical @ 170pF (Typ.)

Ordering Information

| Part No. | Package | Packing |
|---------------|---------|--------------|
| TSM85N10CZ C0 | TO-220 | 50pcs / Tube |

Block Diagram



N-Channel MOSFET

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

| Parameter | Symbol | Limit | Unit | |
|--------------------------------------|-----------------------------------|----------------------|------|---|
| Drain-Source Voltage | V _{DS} | 100 | V | |
| Gate-Source Voltage | V _{GS} | ±25 | V | |
| Continuous Drain Current | I _D | T _C =25°C | 81 | A |
| | | T _C =70°C | 65 | |
| | | T _A =25°C | 8.7 | |
| | | T _A =70°C | 7 | |
| Drain Current-Pulsed Note 1 | I _{DM} | 320 | A | |
| Avalanche Current, L=0.3mH | I _{AS} , I _{AR} | 64 | A | |
| Avalanche Energy, L=0.3mH | E _{AS} , E _{AR} | 620 | mJ | |
| Maximum Power Dissipation | P _D | T _C =25°C | 210 | W |
| | | T _C =70°C | 130 | |
| | | T _A =25°C | 2.4 | |
| | | T _A =70°C | 1.5 | |
| Storage Temperature Range | T _{STG} | -55 to +150 | °C | |
| Operating Junction Temperature Range | T _J | -55 to +150 | °C | |

* Limited by maximum junction temperature

Thermal Performance

| Parameter | Symbol | Limit | Unit |
|--|------------------|-------|------|
| Thermal Resistance - Junction to Case | Rθ _{JC} | 0.6 | °C/W |
| Thermal Resistance - Junction to Ambient | Rθ _{JA} | 52.5 | °C/W |

Notes: Surface mounted on FR4 board t ≤ 10sec

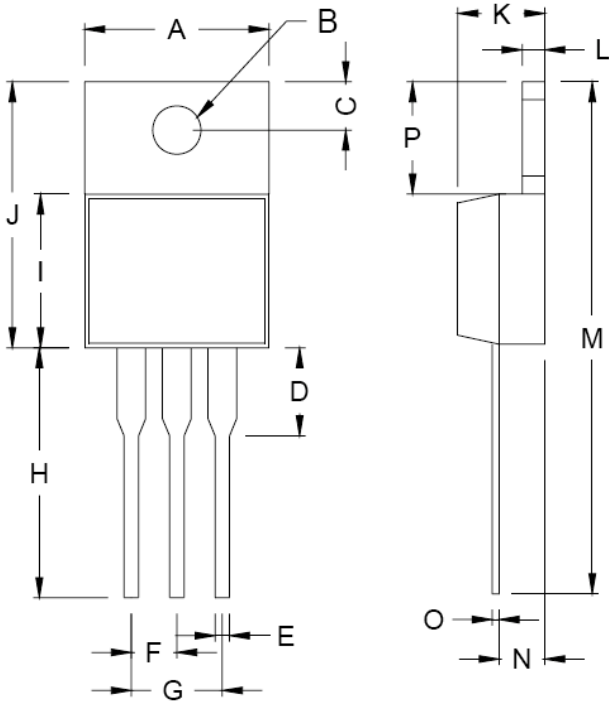
Electrical Specifications (Ta = 25°C unless otherwise noted)

| Parameter | Conditions | Symbol | Min | Typ | Max | Unit |
|--|---|---------------------|-----|------|------|------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | V _{GS} = 0V, I _D = 250uA | BV _{DSS} | 100 | -- | -- | V |
| Drain-Source On-State Resistance | V _{GS} = 10V, I _D = 40A | R _{DS(ON)} | -- | 9 | 10 | mΩ |
| Gate Threshold Voltage | V _{DS} = V _{GS} , I _D = 250uA | V _{GS(TH)} | 2 | 3 | 4 | V |
| Zero Gate Voltage Drain Current | V _{DS} = 80V, V _{GS} = 0V | I _{DSS} | -- | -- | 1 | uA |
| Gate Body Leakage | V _{GS} = ±20V, V _{DS} = 0V | I _{GSS} | -- | -- | ±100 | nA |
| Dynamic | | | | | | |
| Total Gate Charge | V _{DS} = 30V, I _D = 40A, V _{GS} = 10V | Q _g | -- | 154 | -- | nC |
| Gate-Source Charge | | Q _{gs} | -- | 4 | -- | |
| Gate-Drain Charge | | Q _{gd} | -- | 45 | -- | |
| Input Capacitance | V _{DS} = 30V, V _{GS} = 0V, f = 1.0MHz | C _{iss} | -- | 3900 | -- | pF |
| Output Capacitance | | C _{oss} | -- | 300 | -- | |
| Reverse Transfer Capacitance | | C _{rss} | -- | 170 | -- | |
| Switching | | | | | | |
| Turn-On Delay Time | V _{GS} = 10V, V _{DS} = 30V, R _G = 6Ω | t _{d(on)} | -- | 38 | -- | nS |
| Turn-On Rise Time | | t _r | -- | 65 | -- | |
| Turn-Off Delay Time | | t _{d(off)} | -- | 218 | -- | |
| Turn-Off Fall Time | | t _f | -- | 72 | -- | |
| Drain-Source Diode Characteristics and Maximum Rating | | | | | | |
| Drain-Source Diode Forward Voltage | V _{GS} =0V, I _S =20A | V _{SD} | - | 0.8 | 1.2 | V |
| Reverse Recovery Time | I _S = 40A, T _J =25°C di/dt = 100A/us | t _{fr} | | 62 | | nS |
| Reverse Recovery Charge | | Q _{fr} | | 130 | | nC |

Notes:

- Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
- Rθ_{JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Rθ_{JC} is guaranteed by design while Rθ_{CA} is determined by the user's board design. Rθ_{JA} shown below for single device operation on FR-4 in still air

TO-220 Mechanical Drawing



| DIM | TO-220 DIMENSION | | | |
|-----|------------------|--------|--------|-------|
| | MILLIMETERS | | INCHES | |
| | MIN | MAX | MIN | MAX |
| A | 10.000 | 10.500 | 0.394 | 0.413 |
| B | 3.740 | 3.910 | 0.147 | 0.154 |
| C | 2.440 | 2.940 | 0.096 | 0.116 |
| D | - | 6.350 | - | 0.250 |
| E | 0.381 | 1.106 | 0.015 | 0.040 |
| F | 2.345 | 2.715 | 0.092 | 0.058 |
| G | 4.690 | 5.430 | 0.092 | 0.107 |
| H | 12.700 | 14.732 | 0.500 | 0.581 |
| J | 14.224 | 16.510 | 0.560 | 0.650 |
| K | 3.556 | 4.826 | 0.140 | 0.190 |
| L | 0.508 | 1.397 | 0.020 | 0.055 |
| M | 27.700 | 29.620 | 1.060 | 1.230 |
| N | 2.032 | 2.921 | 0.080 | 0.115 |
| O | 0.255 | 0.610 | 0.010 | 0.024 |
| P | 5.842 | 6.858 | 0.230 | 0.270 |

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